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September 2015

# FAN7530 Critical Conduction Mode PFC Controller

### Features

- Low Total Harmonic Distortion (THD)
- Precise Adjustable Output Over-Voltage Protection
- Open-Feedback Protection and Disable Function
- Zero Current Detector
- 150µs Internal Start-up Timer
- MOSFET Over-Current Protection
- Under-Voltage Lockout with 3.5V Hysteresis
- Low Start-up (40µA) and Operating Current (1.5mA)
- Totem Pole Output with High State Clamp
- +500/-800mA Peak Gate Drive Current
- 8-pin DIP or 8-pin SOP

### Applications

- Adapter
- Ballast
- LCD TV, CRT TV
- SMPS

### **Related Application Notes**

■ *AN-6027* - Design of Power Factor Correction Circuit Using FAN7530

### Description

The FAN7530 is an active power factor correction (PFC) controller for the boost PFC applications that operates in critical conduction mode (CRM). It uses the voltage mode PWM that compares an internal ramp signal with the error amplifier output to generate MOSFET turn-off signal. Because the voltage mode CRM PFC controller does not need the rectified AC line voltage information, it can save the power loss of the input voltage sensing network necessary for the current mode CRM PFC controller.

FAN7530 provides many protection functions such as over voltage protection, open-feedback protection, overcurrent protection, and under-voltage lockout protection. The FAN7530 can be disabled if the INV pin voltage is lower than 0.45V and the operating current decreases to  $65\mu$ A. Using a new variable on-time control method, THD is lower than the conventional CRM boost PFC ICs.

### **Ordering Information**

| Part Number | Operating Temp.<br>Range | Pb-Free | Package | Packing Method | Marking<br>Code |
|-------------|--------------------------|---------|---------|----------------|-----------------|
| FAN7530N    | -40°C to +125°C          | Yes     | 8-DIP   | Rail           | FAN7530         |
| FAN7530M    | -40°C to +125°C          | Yes     | 8-SOP   | Rail           | FAN7530         |
| FAN7530MX   | -40°C to +125°C          | Yes     | 8-SOP   | Tape & Reel    | FAN7530         |



### **Pin Assignments**



Figure 3. Pin Configuration (Top View)

### **Pin Definitions**

| Pin # | Name            | Description  |
|-------|-----------------|--|
| 1     | INV             | This pin is the inverting input of the error amplifier. The output voltage of the boost PFC converter should be resistively divided to 2.5V.   |
| 2     | МОТ             | This pin is used to set the slope of the internal ramp. The voltage of this pin is main-<br>tained at 3V. If a resistor is connected between this pin and GND, current flows out of<br>the pin and the slope of the internal ramp is proportional to this current. |
| 3     | COMP            | This pin is the output of the transconductance error amplifier. Components for the output voltage compensation should be connected between this pin and GND.   |
| 4     | CS              | This pin is the input of the over-current protection comparator. The MOSFET current is sensed using a sensing resistor and the resulting voltage is applied to this pin. An internal RC filter is included to filter switching noise.                              |
| 5     | ZCD             | This pin is the input of the zero current detection block. If the voltage of this pin goes higher than 1.5V, then goes lower than 1.4V, the MOSFET is turned on.   |
| 6     | GND             | This pin is used for the ground potential of all the pins. For proper operation, the signal ground and the power ground should be separated.   |
| 7     | OUT             | This pin is the gate drive output. The peak sourcing and sinking current levels are +500mA and -800mA respectively. For proper operation, the stray inductance in the gate driving path must be minimized.   |
| 8     | V <sub>CC</sub> | This pin is the IC supply pin. IC current and MOSFET drive current are supplied using this pin.  |

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A = 25^{\circ}C$  unless otherwise specified.

| Symbol                            | Parameter   | Value      | Unit |
|-----------------------------------|---|------------|------|
| V <sub>CC</sub>                   | Supply Voltage  | Vz         | V    |
| I <sub>OH</sub> , I <sub>OL</sub> | Peak Drive Output Current                                     | +500/-800  | mA   |
| I <sub>clamp</sub>                | Driver Output Clamping Diodes $V_O > V_{CC}$ or $V_O < -0.3V$ | ±10        | mA   |
| I <sub>det</sub>                  | Detector Clamping Diodes                                      | ±10        | mA   |
| V <sub>IN</sub>                   | Error Amplifier, MOT, CS Input Voltages                       | -0.3 to 8  | V    |
| Тj                                | Operating Junction Temperature                                | 150        | °C   |
| T <sub>A</sub>                    | Operating Temperature Range                                   | -40 to 125 | °C   |
| T <sub>stg</sub>                  | Storage Temperature Range                                     | -65 to 150 | °C   |
| V <sub>ESD_HBM</sub>              | ESD Capability, Human Body Model                              | 2.0        | kV   |
| V <sub>ESD_MM</sub>               | ESD Capability, Machine Model                                 | 300        | V    |
| V <sub>ESD_CDM</sub>              | ESD Capability, Charged Device Model                          | 500        | V    |

### Thermal Impedance<sup>(1)</sup>

| Symbol | Parameter                               |       | Value | Unit |
|--------|---|-------|-------|------|
| Rθja   | Thermal Registeres, Junction to Ambient | 8-DIP | 110   | °C/W |
|        |   | 8-SOP | 150   | °C/W |

### Note:

1. Regarding the test environment and PCB type, please refer to JESD51-2 and JESD51-10.

### **Electrical Characteristics**

 $V_{CC}$  = 14V,  $T_A$  = -40°C~125°C, unless otherwise specified.

| Symbol                 | Parameter   | Condition                                      | Min.  | Тур.  | Max.  | Unit |
|------------------------|---|--|-------|-------|-------|------|
| UNDER-VO               | LTAGE LOCKOUT SECTION                                     |  |       |       | 1     |      |
| V <sub>th(start)</sub> | Start Threshold Voltage                                   | V <sub>CC</sub> increasing                     | 11    | 12    | 13    | V    |
| V <sub>th(stop)</sub>  | Stop Threshold Voltage                                    | V <sub>CC</sub> decreasing                     | 7.5   | 8.5   | 9.5   | V    |
| HY <sub>(uvlo)</sub>   | UVLO Hysteresis   |  | 3.0   | 3.5   | 4.0   | V    |
| VZ                     | Zener Voltage   | $I_{CC} = 20 \text{mA}$                        | 20    | 22    | 24    | V    |
| SUPPLY CU              | JRRENT SECTION  |  | •     |       | •     |      |
| I <sub>st</sub>        | Start-up Supply Current                                   | $V_{CC} = V_{th(start)} - 0.2V$                |       | 40    | 70    | μA   |
| I <sub>CC</sub>        | Operating Supply Current                                  | Output no switching                            |       | 1.5   | 3.0   | mA   |
| I <sub>dcc</sub>       | Dynamic Operating Supply Current                          | 50kHz, Cl=1nF                                  |       | 2.5   | 4.0   | mA   |
| I <sub>CC(dis)</sub>   | Operating Current at Disable                              | V <sub>inv</sub> = 0V                          | 20    | 65    | 95    | μA   |
| ERROR AN               | IPLIFIER SECTION  |  |       |       | I.    |      |
| V <sub>ref1</sub>      | Voltage Feedback Input Threshold1                         | $T_A = 25^{\circ}C$                            | 2.465 | 2.500 | 2.535 | V    |
| $\Delta V_{ref1}$      | Line Regulation   | $V_{CC} = 14V \sim 20V$                        |       | 0.1   | 10.0  | mV   |
| $\Delta V_{ref2}$      | Temperature Stability of V <sub>ref1</sub> <sup>(2)</sup> |  |       | 20    |       | mV   |
| I <sub>b(ea)</sub>     | Input Bias Current  | $V_{inv} = 1V \sim 4V$                         | -0.5  |       | 0.5   | μA   |
| I <sub>source</sub>    | Output Source Current                                     | $V_{inv} = V_{ref1} - 0.1V$                    |       | -12   |       | μA   |
| I <sub>sink</sub>      | Output Sink Current                                       | $V_{inv} = V_{ref1} + 0.1V$                    |       | 12    |       | μA   |
| V <sub>eao(H)</sub>    | Output Upper Clamp Voltage                                | $V_{inv} = V_{ref1} - 0.1V$                    | 5.4   | 6.0   | 6.6   | V    |
| V <sub>eao(Z)</sub>    | Zero Duty Cycle Output Voltage                            |  | 0.9   | 1.0   | 1.1   | V    |
| 9 <sub>m</sub>         | Transconductance <sup>(2)</sup>                           |  | 90    | 115   | 140   | µmho |
| MAXIMUM                | ON-TIME SECTION   | ·  | •     |       |       |      |
| V <sub>mot</sub>       | Maximum On-time Voltage                                   | $R_{mot} = 40.5 k\Omega$                       | 2.784 | 2.900 | 3.016 | V    |
| T <sub>on(max)</sub>   | Maximum On-time Programming                               | $R_{mot} = 40.5 k\Omega$ , $T_A = 25^{\circ}C$ | 19    | 24    | 29    | μs   |
| CURRENT                | SENSE SECTION   |  |       |       |       |      |
| V <sub>CS(limit)</sub> | Current Sense Input Threshold<br>Voltage Limit            |  | 0.7   | 0.8   | 0.9   | V    |
| I <sub>b(cs)</sub>     | Input Bias Current  | $V_{CS} = 0V \sim 1V$                          | -1.0  | -0.1  | 1.0   | μA   |
| t <sub>d(cs)</sub>     | Current Sense Delay to Output <sup>(2)</sup>              | dV/dt = 1V/100ns,<br>From 0V to 5V             |       | 350   | 500   | ns   |

Note:

2. These parameters, although guaranteed by design, are not tested in mass production.

### Electrical Characteristics (Continued)

 $V_{CC}$  = 14V,  $T_A$  = -40°C~125°C, unless otherwise specified.

| Symbol                   | Parameter   | Condition                                      | Min.  | Тур.  | Max.  | Unit |
|--------------------------|---|--|-------|-------|-------|------|
| ZERO CURR                | ENT DETECT SECTION                                      |  |       |       |       |      |
| V <sub>th(ZCD)</sub>     | Input Voltage Threshold <sup>(3)</sup>                  |  | 1.35  | 1.50  | 1.65  | V    |
| HY <sub>(ZCD)</sub>      | Detect Hysteresis <sup>(3)</sup>                        |  | 0.05  | 0.10  | 0.15  | V    |
| V <sub>clamp(H)</sub>    | Input High Clamp Voltage                                | I <sub>det</sub> = 3mA                         | 6.0   | 6.7   | 7.4   | V    |
| V <sub>clamp(L)</sub>    | Input Low Clamp Voltage                                 | I <sub>det</sub> = -3mA                        | 0     | 0.65  | 1.00  | V    |
| I <sub>b(ZCD)</sub>      | Input Bias Current                                      | $V_{ZCD} = 1V \sim 5V$                         | -1.0  | -0.1  | 1.0   | μA   |
| I <sub>source(zcd)</sub> | Source Current Capability <sup>(3)</sup>                | $T_A = 25^{\circ}C$                            |       |       | -10   | mA   |
| I <sub>sink(zcd)</sub>   | Sink Current Capability <sup>(3)</sup>                  | $T_A = 25^{\circ}C$                            |       |       | 10    | mA   |
| t <sub>dead</sub>        | Maximum Delay from ZCD to Output Turn-on <sup>(3)</sup> | dV/dt = -1V/100ns,<br>From 5V to 0V            | 100   |       | 200   | ns   |
| OUTPUT SE                | CTION   |  | •     |       |       |      |
| V <sub>OH</sub>          | Output Voltage High                                     | I <sub>O</sub> = -100mA, T <sub>A</sub> = 25°C | 9.2   | 11.0  | 12.8  | V    |
| V <sub>OL</sub>          | Output Voltage Low                                      | I <sub>O</sub> = 200mA, T <sub>A</sub> = 25°C  |       | 1.0   | 2.5   | V    |
| t <sub>r</sub>           | Rising Time <sup>(3)</sup>                              | CI = 1nF                                       |       | 50    | 100   | ns   |
| t <sub>f</sub>           | Falling Time <sup>(3)</sup>                             | CI = 1nF                                       |       | 50    | 100   | ns   |
| V <sub>O(max)</sub>      | Maximum Output Voltage                                  | V <sub>CC</sub> = 20V, I <sub>O</sub> = 100µA  | 11.5  | 13.0  | 14.5  | V    |
| V <sub>O(UVLO)</sub>     | Output Voltage with UVLO Activated                      | V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA   |       |       | 1     | V    |
| RESTART TI               | MER SECTION   |  |       |       |       |      |
| t <sub>d(rst)</sub>      | Restart Timer Delay                                     |  | 50    | 150   | 300   | μs   |
| OVER-VOLT                | AGE PROTECTION SECTION                                  |  |       |       |       |      |
| V <sub>ovp</sub>         | OVP Threshold Voltage                                   | $T_A = 25^{\circ}C$                            | 2.620 | 2.675 | 2.730 | V    |
| HY <sub>(ovp)</sub>      | OVP Hysteresis  | $T_A = 25^{\circ}C$                            | 0.120 | 0.175 | 0.230 | V    |
| ENABLE SE                | CTION   |  | ·     | •     |       |      |
| V <sub>th(en)</sub>      | Enable Threshold Voltage                                |  | 0.40  | 0.45  | 0.50  | V    |
| HY <sub>(en)</sub>       | Enable Hysteresis                                       |  | 0.05  | 0.10  | 0.15  | V    |

Note:

3. These parameters, although guaranteed by design, are not tested in mass production.

### **Typical Characteristics**



Figure 4. Start Threshold Voltage vs. Temp.



Figure 6. UVLO Hysteresis vs. Temp.







Figure 5. Stop Threshold Voltage vs. Temp.



Figure 7. Zener Voltage vs. Temp.







90

Typical Characteristics (Continued)

4





Figure 16. Output Sink Current vs. Temp.



Figure 18. Zero Duty Cycle Output Voltage vs. Temp.



Figure 17. Output Upper Clamp Voltage vs. Temp.



Figure 19. Maximum On-Time Voltage vs. Temp.





# Typical Characteristics (Continued)

Figure 22. Input Bias Current vs. Temp.



Figure 24. Input Low Clamp Voltage vs. Temp.







Figure 23. Input High Clamp Voltage vs. Temp.



Figure 25. Input Bias Current vs. Temp.







Figure 28. Restart Delay Time vs. Temp.



Figure 29. OVP Threshold Voltage vs. Temp.



Figure 30. OVP Hysteresis vs. Temp.





Figure 31. Enable Threshold voltage vs. Temp.

### **Applications Information**

### 1. Error Amplifier Block

The error amplifier block consists of a transconductance amplifier, output OVP comparator, and disable comparator. For the output voltage control, a transconductance amplifier is used instead of the conventional voltage amplifier. The transconductance amplifier (voltage controlled current source) aids the implementation of OVP and disable function. The output current of the amplifier changes according to the voltage difference of the inverting and non-inverting input of the amplifier. The output voltage of the amplifier is compared with the internal ramp signal to generate the switch turn-off signal. The OVP comparator shuts down the output drive block when the voltage of the INV pin is higher than 2.675V and there is 0.175V hysteresis. The disable comparator disables the operation of the FAN7530 when the voltage of the inverting input is lower than 0.45V and there is 100mV hysteresis. An external small signal MOSFET can be used to disable the IC, as shown in Figure 33. The IC operating current decreases below 65µA to reduce power consumption if the IC is disabled.



Figure 33. Error Amplifier Block

### 2. Zero Current Detection Block

The zero current detector (ZCD) generates the turn-on signal of the MOSFET when the boost inductor current reaches zero using an auxiliary winding coupled with the inductor. If the voltage of the ZCD pin goes higher than 1.5V, the ZCD comparator waits until the voltage goes below 1.4V. If the voltage goes below 1.4V, the zero cur-

rent detector turns on the MOSFET. The ZCD pin is protected internally by two clamps, 6.7V-high clamp and 0.65V-low clamp. The 150µs timer generates a MOSFET turn-on signal if the drive output has been low for more than 150µs from the falling edge of the drive output.



Figure 34. Zero Current Detector Block

### 3. Sawtooth Generator Block

The output of the error amplifier and the output of the sawtooth generator are compared to determine the MOSFET turn-off instance. The slope of the sawtooth is determined by an external resistor connected to the MOT pin. The voltage of the MOT pin is 2.9V and the slope is proportional to the current flowing out of the MOT pin. The internal ramp signal has a 1V offset; therefore, the drive output is shut down if the voltage of the COMP pin is lower than 1V. The MOSFET on-time is maximum when the COMP pin voltage is 5V. According to the slope of the internal ramp, the maximum on-time can be programmed. The necessary maximum on-time depends on the boost inductor, lowest AC line voltage, and maximum output power. The resistor value should be designed properly.





### 4. Over-Current Protection Block

The MOSFET current is sensed using an external sensing resistor for the over-current protection. If the CS pin voltage is higher than 0.8V, the over-current protection comparator generates a protection signal. An internal RC filter is included to filter switching noise.



Figure 36. Over-Current Protection Block

### 5. Switch Drive Block

The FAN7530 contains a single totem-pole output stage designed for a direct drive of the power MOSFET. The drive output is capable of up to +500/-800mA peak current with a typical rise and fall time of 50ns with 1nF load. The output voltage is clamped to 13V to protect the MOSFET gate even if the V<sub>CC</sub> voltage is higher than 13V.

### 6. Under-Voltage Lockout Block

If the V<sub>CC</sub> voltage reaches 12V, the IC's internal blocks are enabled and start operation. If the V<sub>CC</sub> voltage drops below 8.5V, most of the internal blocks are disabled to reduce the operating current. V<sub>CC</sub> voltage should be higher than 8.5V under normal conditions.

# FAN7530 Critical Conduction Mode PFC Controller

### Typical application circuit

| Application | Output Power | Input Voltage                  | Output Voltage |
|-------------|--------------|--------------------------------|----------------|
| Ballast     | 100W         | Universal input<br>(85~265Vac) | 400V           |

### Features

- High efficiency (>90% at 85Vac input)
- Low THD (total harmonic distortion) (<10% at 265Vac input, 25W load)

### **Key Design Notes**

R1, R2, R5, C11 should be optimized for best THD characteristic.

### 1. Schematic



### Figure 37. Schematic

### 2. Inductor Schematic Diagram



### Figure 38. Inductor Schematic Diagram

### 3. Winding Specification

| No   | Pin (s→f)  | Wire                    | Turns | Winding Method   |  |  |  |
|--|--|-------------------------|-------|------------------|--|--|--|
| Np   | $5 \rightarrow 3$                                | $0.1^{\circ} \times 30$ | 58    | Solenoid Winding |  |  |  |
| Insulation: P  | Insulation: Polyester Tape t = 0.050mm, 4 Layers |                         |       |                  |  |  |  |
| N <sub>Vcc</sub>                                       | $2 \rightarrow 4$                                | $0.2^{\phi} 	imes 10$   | 8     | Solenoid Winding |  |  |  |
| Outer Insulation: Polyester Tape t = 0.050mm, 4 Layers |  |                         |       |                  |  |  |  |
| Air Gap: 0.6mm for each leg                            |  |                         |       |                  |  |  |  |

### 4. Electrical Characteristics

|            | Pin   | Specification | Remarks    |
|------------|-------|---------------|------------|
| Inductance | 3 - 5 | 600µH ± 10%   | 100kHz, 1V |

### 5. Core & Bobbin

- Core: El 3026
- Bobbin: EI3026
- Ae(mm<sup>2</sup>): 111

### 6. Demo Circuit Part List

| Part | Value        | Note                            | Note Part    |            | Note       |  |
|------|--------------|---------------------------------|--------------|------------|------------|--|
|      | Fuse         | 9                               |              | Inductor   | •          |  |
| F1   | 3A/250V      |                                 | T1           | 600µH      | EI3026     |  |
|      | NTC          |                                 |              |            |            |  |
| NTC  | 10D-9        |                                 | MOSFET       |            |            |  |
|      | Resistor     |                                 |              | FQPF13N50C | Fairchild  |  |
| R1   | 56k $\Omega$ | 1/4W                            |              |            |            |  |
| R2   | 820kΩ        | 1/4W                            |              | Diode      |            |  |
| R3   | 330kΩ        | 1/2W                            | D1           | 1N4148     | Fairchild  |  |
| R4   | 150Ω         | 1/2W                            | D2           | BYV26C     | 600V, 1A   |  |
| R5   | 20kΩ         | 1/4W                            | D3           | SB140      | Fairchild  |  |
| R6   | 10Ω          | 1/4W                            | ZD1          | 1N4746     | 18V        |  |
| R7   | 0.2Ω         | 1/2W                            |              |            |            |  |
| R8   | R8 10kΩ 1/4W |                                 |              |            |            |  |
| R9   | R9 10kΩ 1/4W |                                 | Bridge Diode |            |            |  |
| R10  | 2MΩ          | 1/4W                            | BD           | KBL06      | 600V/4A    |  |
| R11  | 12.9kΩ       | 1/4W                            |              |            |            |  |
|      |              |                                 | Line Filter  |            |            |  |
|      | Capacitor    |                                 |              | 40mH       | Wire 0.4mm |  |
| C1   | 150nF/275VAC | Box Capacitor                   |              |            |            |  |
| C2   | 470nF/275VAC | Box Capacitor                   | IC           |            |            |  |
| C3   | 2.2nF/3kV    | Ceramic Capacitor               | IC1          | FAN7530    | Fairchild  |  |
| C4   | 2.2nF/3kV    | Ceramic Capacitor               |              |            |            |  |
| C5   |              |                                 |              | TNR        |            |  |
| C6   | 47µF/25V     | Electrolytic Capacitor          | V1           | 471        | 470V       |  |
| C7   | 47nF/50V     | Ceramic Capacitor               |              |            |            |  |
| C8   | 220nF/50V    | Multilayer Ceramic<br>Capacitor |              |            |            |  |
| C9   | 100µF/450V   | Electrolytic Capacitor          |              |            |            |  |
| C10  | 12nF/100V    | Film Capacitor                  |              |            |            |  |
| C11  | 56pF/50V     | Ceramic Capacitor               |              |            |            |  |

### 7. Layout



### Figure 39. PCB Layout Considerations for FAN7530

### 8. Performance Data

| P <sub>OUT</sub> |            | 85Vac | 115Vac | 230Vac | 265Vac |
|------------------|------------|-------|--------|--------|--------|
|                  | PF         | 0.998 | 0.998  | 0.991  | 0.984  |
| 100W             | THD        | 5.1%  | 3.6%   | 5.2%   | 6.2%   |
|                  | Efficiency | 90.9% | 93.7%  | 95.6%  | 96%    |
|                  | PF         | 0.999 | 0.998  | 0.986  | 0.975  |
| 75W              | THD        | 4.1%  | 3.6%   | 5.0%   | 5.7%   |
|                  | Efficiency | 91.6% | 93.3%  | 94.6%  | 95.3%  |
|                  | PF         | 0.998 | 0.997  | 0.974  | 0.956  |
| 50W              | THD        | 4.4%  | 5.0%   | 5.7%   | 6.2%   |
|                  | Efficiency | 91.3% | 91.9%  | 92.7%  | 93.4%  |
|                  | PF         | 0.995 | 0.991  | 0.923  | 0.876  |
| 25W              | THD        | 7.9%  | 8.6%   | 8.3%   | 8.7%   |
|                  | Efficiency | 86.4% | 87.1%  | 87.3%  | 88.1%  |



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